



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group art unit: 3663
Examiner: Johannes P. Mondt

pw

In Re PATENT APPLICATION of:

Applicant(s): Mitsuhiro OHIGARA et al.)
Serial No.: 10/743,104)
Filed: December 23, 2003)
For: COMBINED SEMICONDUCTOR)
APPARATUS WITH SEMICONDUCTOR)
THIN FILM)
Atty. ref.: MAE 305)

December 5, 2007

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This is an Information Disclosure Statement submitted in compliance with the timing requirements of 37 C.F.R. §1.97(c)(1), i.e., after the mailing of a first Office Action on the merits, but before the mailing date of a final Action or Notice of Allowance.

Attached are copies of two Japanese patent documents with their English-language abstracts, from which any relevance of the documents can be gleaned. The documents are listed on the attached form PTO-1449. The documents were first cited in the attached foreign Office Action mailed on November 27, 2007, issued in connection with the counterpart Japanese patent application No. 2002-371724.

It is hereby certified that each item of information contained in the Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement.

Since this Information Disclosure Statement is being filed with certification and before the mailing date of a final action or Notice of Allowance, no fee is required, and the requirements of 37 C.F.R. §§1.97 and 1.98 are deemed to be fully met as to all documents listed. Consideration of the listed documents respectfully is requested.

Should any fee be required, however, the Director is hereby authorized to charge the fee to our Deposit Account No. 18-0002.

Respectfully submitted,

Robert H. Berdo, Jr. – Reg. No. 38,075
RABIN & BERDO, PC – Customer No. 23995
Telephone: (202) 371-8976
Fax: (202) 408-0924

December 5, 2007

Date

RHB/vm